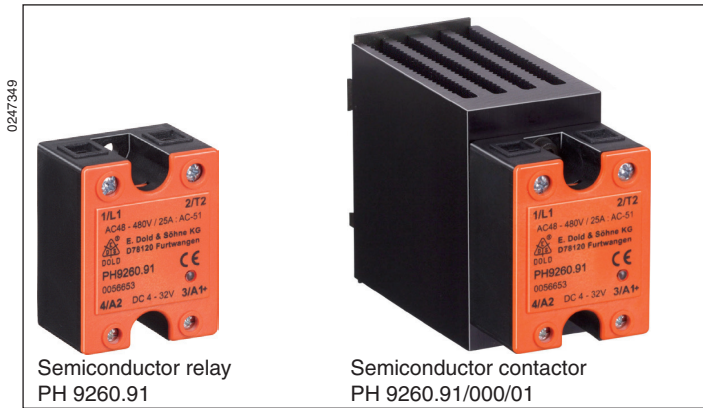# Power Electronics

POWERSWITCH
Semiconductor Relay / - Contactor
## PH 9260

DOLD ®

Semiconductor relay
PH 9260.91

Semiconductor contactor
PH 9260.91/000/01

- AC semiconductor relay / -contactor
- According to IEC/EN 60947-4-3
- Load current up to 125 A, AC 51 with I^2t up to 18000 A^2s
- Switching at cero crossing
- As option switching at voltage maximum
- 2 anti-parallel thyristors
- DCB technology (direct bonding method) for excellent heat transmission properties
- Touch protection IP20
- Box terminals
- LED status indicator
- Peak reverse voltage 1200 V or 1600 V
- Insulation voltage 4000 V
- As option with overtemperature protection
- As option with reduced HF-emission
- As option with heat sink, for DIN rail mounting
- Width: 45 mm

Function Diagram

M8929_a

Δt = max. 20ms; zero crossing control

Circuit Diagram

M8729_b

PH 9260.91
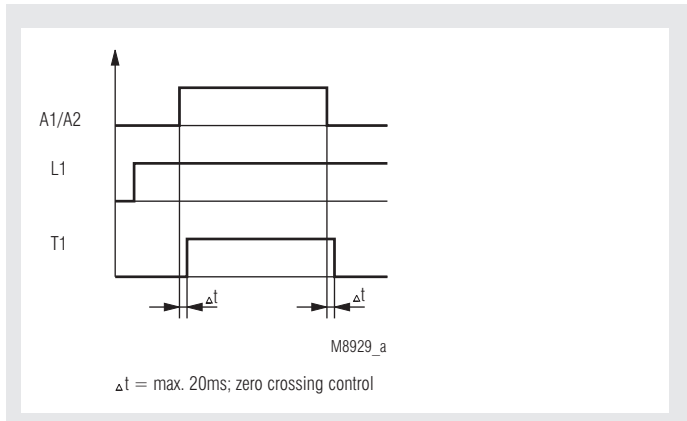
Applications

Solid state relays switching at zero crossing:

For frequent no-wear and no-noise switching of

- heating systems

- motors

- valves

- lighting systems

The semiconductor relay switches at zero crossing and is suitable for many applications e.g. extrusion machines for plastic and rubber, packaging machines, solder lines, machines in food industry.

Solid state relays switching at voltage maximum:

he solid state relay PH 9260/020 switching at voltage maximum is suitable to switch transformers. The usual high inrush current does not occur.
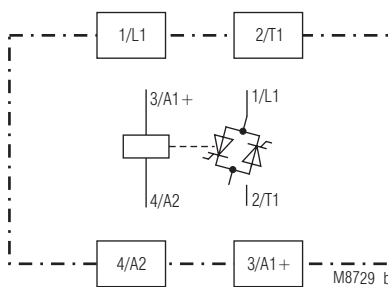
Function

The semiconductor relay PH 9260 is designed whith 2 anti-parallel connected thyristors switching at zero crossing.

When connecting the control voltage the output of the semiconductor relay is activated at the next zero crossing of the sinusoidal voltage. When disconnecting the control voltage the output is switched off at the next zero crossing of the load courrent.

The LED shows the state of the control input.

As option the semiconductor relay is available with heatsink to be mounted on DIN rail. This provides optimum heat transmission.

Notes

Overtemperature protection
Optionally, the semiconductor relay has an overtemperature protection to monitor the temperature of the heat sink. To this end, a thermal release switch (NC contact) can be inserted into the respective pocket at the bottom of the semiconductor relay. As soon as the temperature of the heat sink exceeds for example 100°C, the thermal release switch. For thermal protection of the semiconductor relay, a thermal release switch of UCHIYA type UP62 – 100 can be installed.

Output

Load voltage AC [V]:

PH 9260:	24 ... 240, 48 ... 480, 48 ... 600		
PH 9260/020:	100 ... 240, 200 ... 480		

Frequency range [Hz]:	47 ... 63			
Load current [A], AC-51: PH 9260, PH 9260/020:	25	50	100[1]	125[1]
Load current [A], AC-56a: PH 9260/020:	10 -	20 30[3]	- -	- -
Load limit integral I²t [A²s]:	800	1800 6600[2]	6600	18000
Max. overload current [A] t = 10 ms:	400	600 1150[2]	1150	1900
Periodic overload current t = 1 s [A]:	40	120 150[2]	150	200
Min. current [mA]:	20			
On-state voltage at nominal current [V]:	1.2	1.4	1.4	1.3
Rate of rise of off-state voltage [V/µs]:	500	500	1000	1000
Rate of rise of current [A/µs]:	100	100	100	150

Temperature Data

Thermal resistance junction - housing [K/W]:	0.6	0.5	0.3	0.3
Thermal resistance housing - ambient [K/W]:	12	12	12	12
Junction temperature [°C]:	≤ 125			

[1] Only for pulse operation: Please make sure, that the mean value of the current does not exceed 50 A on these devices.

[2] Variant PH 9260.91/1_ _

[3] Variant PH 9260.91/120

Control Circuit

	DC	AC/DC	AC/DC
Control voltage range [V]:	4 ... 32	18 ... 36	100 ... 240
Max. nominal input current [mA]: PH 9260:	12	25 (AC) 12 (DC)	5 bei 240 V AC (regulated)
Max. nominal input current [mA]: PH 9260/020:	20	-	-
Turn-on delay [ms]:	5 + 1/2 cycle		
Turn-off delay [ms]			
at AC/DC 18 ...36 V:	20 + 1/2 cycle		
at AC/DC 85 ... 265 V:	30 + 1/2 cycle		

General Data

Operating mode:	Continuous operation	
Temperature range:		
operation:	- 20 ... 40° C	
storage:	- 20 ... 80° C	
Clearance and creepage distances		
rated impulse voltage / pollution degree:	6 kV / 3	IEC/EN 60 664-1
EMC:	IEC/EN 61 000-6-4,	IEC/EN 61 000-4-1
Electrostatic discharge (ESD):	8 kV air / 6 kV contact	IEC/EN 61 000-4-2
HF irradiation:	10 V / m	IEC/EN 61 000-4-3
Fast transients:	2 kV	IEC/EN 61 000-4-4
Surge voltages between		
wires for power supply:	1 kV	IEC/EN 61 000-4-5
between wire and ground:	2 kV	IEC/EN 61 000-4-5
HF-wire guided	10 V	IEC/EN 61 000-4-6
Interference suppression:	Limit value class A	IEC/EN 60 947-4-3

Degree of protection		
Housing:	IP 40	IEC/EN 60 529
Terminals:	IP 20	IEC/EN 60 529
Vibration resistance:	Amplitude 0.35 mm frequency 10 ... 55 Hz, IEC/EN 60-068-2-6	
Housing material:	Fiberglass reinforced polycarbonate Flame resistant: UL 94 V0	
Base plate:	Aluminum, copper nickle-plated	
Potting compound:	Polyurethane	
Mounting screws:	M5 x 8 mm	
Mounting torque:	2.5 Nm	
Connections control circuit:	Mounting screws M3 Pozidrive 2 PT	
Mounting torque:	0.5 Nm	
Wire cross section:	1.5 mm² wire	
Connections load circuit:	Mounting screws M4 Pozidrive 1 PT	
Mounting torque:	1.2 Nm	
Wire cross section:	10 mm² wire	
Nominal insulation voltage		
Control circuit – load circuit:	4 kV$_{eff.}$	
Load circuit – base plate:	4 kV$_{eff.}$	
Overvoltage category:	II	
Weight		
without heat sink:	approx. 120 g	
PH 9260.91/_ _ _ /01:	approx. 550 g	
PH 9260.91/_ _ _ /02:	approx. 670 g	

Dimensions

Width x height x depth		
without heat sink:	45 x 58 x 32 mm	
PH 9260.91/_ _ _ /01:	45 x 80 x 124 mm	
PH 9260.91/_ _ _ /02:	45 x 100 x 124 mm	

UL-Data

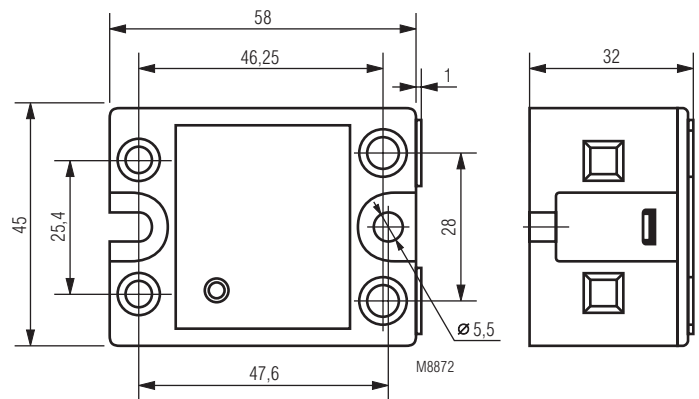|	
Control voltage:	DC 4 ... 32 V, Class 2 or current / voltage limiting acc. to UL 508
Load type:	Resistive
Wire connection:	Copper conductors only
3A1+ / 4A2:	AWG 18 - 14 Torque 0.5 Nm
1L1 / 2T1:	AWG 16 - 8 Torque 1.8 Nm

info **Technical data that is not stated in the UL-Data, can be found in the technical data section.**

Dimensions

M8872

Accessories

PH 9260-0-12: Graphite foil 55 x 40 x 0.25 mm to be fitted between device and heat sink, for better heat transmission Article number: 0058395

For the 100 A- and 125 A-variants we recommend a 25 mm² adapter terminal type 802/115S, Brand FTG.

Technical Data

Contents of Article Numbers

Type		PH 9260							
Variant (Designation)		Standard	PH 9260/000/01 with heat sink	Standard	PH 9260/000/02 with heat sink	PH 9260/100 (I^2t = 6600 A²s)	PH 9260/100/02 (I^2t = 6600 A²s with heat sink)	Standard	Standard
Load current		25 A	25 A	50 A	50 A[3]	50 A	50 A[3]	100 A	125 A
Load voltage	**Control voltage**								
24 ... 240 V AC	4 ... 32 V DC	0056651	0056953	0056652	0056954	0057699	0058195	0056821	0059736
	18 ... 36 V AC/DC	0063505	0063676	*	*	*	*	*	*
	100 ... 240 V AC/DC	0061422	0058255	0059749	0058256	*	*	0059631	*
48 ... 480 V AC	4 ... 32 V DC	0056653	0056955	0056654	0056956	0057700	0058196	0056822	0059737
	18 ... 36 V AC/DC	*	*	*	*	*	*	*	*
	100 ... 240 V AC/DC	0059690	0061943	0059691	0059074	*	*	0063193	*
48 ... 600 V AC	4 ... 32 V DC	0058676	*	*	0059980	0058678	*	0058677	*
	18 ... 36 V AC/DC	*	*	0058958	*	0058960	*	*	*
	100 ... 240 V AC/DC	*	*	0058959	*	0058961	*	*	*

At devices without heatsink the necessary heatsink has to be chosen according to the dimensioning notes.

* On request

Units with UL-Approval

[3] for stepping operation with 80 % ED

Standard Type
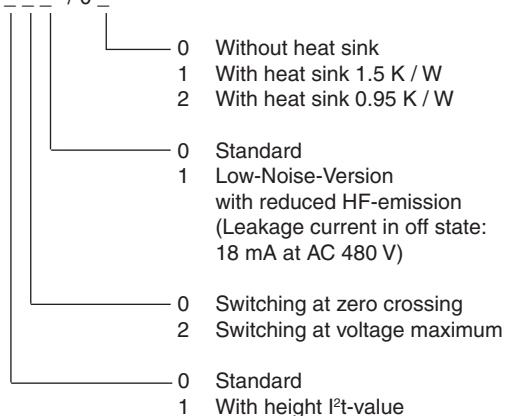
PH 9260.91   AC 48 ... 480 V   50 A   DC 4 ... 32 V
Article number: 0056654
- Load voltage: AC 48 ... 480 V
- Load current: 50 A
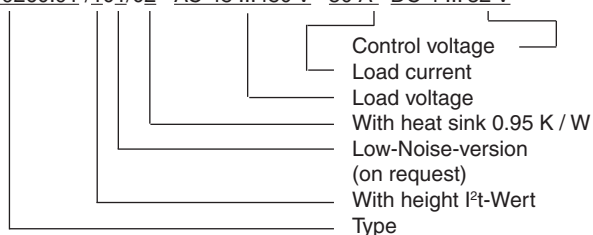- Control voltage: DC 4 ... 32 V
- Width: 45 mm

Variantes

PH 9260 .91   / _ _ _   / 0 _

- 0   Without heat sink
- 1   With heat sink 1.5 K / W
- 2   With heat sink 0.95 K / W

- 0   Standard
- 1   Low-Noise-Version
  with reduced HF-emission
  (Leakage current in off state:
  18 mA at AC 480 V)

- 0   Switching at zero crossing
- 2   Switching at voltage maximum

- 0   Standard
- 1   With height I^2t-value

Ordering example for variants

PH 9260.91 /101/02   AC 48 ...480 V   50 A   DC 4 ... 32 V

- Control voltage
- Load current
- Load voltage
- With heat sink 0.95 K / W
- Low-Noise-version (on request)
- With height I^2t-Wert
- Type

Selection of a Heat Sink

Load current (A)	PH 9260 25 A Thermal resistance (K/W)					
25.0	2.8	2.5	2.1	1.8	1.5	1.1
22.5	3.2	2.8	2.5	2.1	1.7	1.3
20.0	3.7	3.3	2.8	2.4	2.0	1.6
17.5	4.3	3.8	3.4	2.8	2.4	1.9
15.0	5.1	4.6	4.0	3.5	2.9	2.4
12.5	6.3	5.6	5.0	4.3	3.6	2.8
10.0	8.0	7.2	6.4	5.6	4.7	3.9
7.5	11.0	9.9	8.7	7.6	6.5	5.4
5.0	16.8	15.0	13.5	12.0	10.0	8.5
2.5	-	-	-	-	21.0	17.6
	20	30	40	50	60	70
	Ambient-temperature (°C)					

Load current (A)	PH 9260 50 A Thermal resistance (K/W)					
50	0.9	0.7	0.6	0.4	0.3	-
45	1.0	0.9	0.7	0.5	0.4	0.2
40	1.2	1.0	0.9	0.7	0.5	0.3
35	1.5	1.3	1.0	0.9	0.7	0.5
30	1.9	1.6	1.4	1.1	0.9	0.7
25	2.4	2.0	1.8	1.5	1.2	0.9
20	3.0	2.7	2.4	2.0	1.9	1.3
15	4.4	3.9	3.4	2.9	2.5	2.0
10	6.9	6.0	5.4	4.7	4.0	3.3
5	14.0	12.9	11.5	10.0	8.6	7.2
	20	30	40	50	60	70
	Ambient-temperature (°C)					

Load current (A)	PH 9260 100 A Thermal resistance (K/W)					
100	0.43	0.35	0.25	0.2	-	-
90	0.56	0.46	0.35	0.28	0.2	-
80	0.7	0.6	0.5	0.4	0.3	0.2
70	0.9	0.8	0.65	0.55	0.4	0.3
60	1.2	1.0	0.9	0.75	0.6	0.46
50	1.6	1.4	1.2	1.0	0.85	0.6
40	2.3	2.0	1.8	1.5	1.2	1.0
30	3.4	3.0	2.5	2.2	2.0	1.5
20	5.6	5.0	4.5	3.9	3.3	2.7
10	12.0	11.0	10.0	9.0	7.6	6.0
	20	30	40	50	60	70
	Ambient-temperature (°C)					

| Load current (A)	PH 9260 125 A Thermal resistance (K/W)					
125	0.5	0.4	0.3	0.2	0.1	0.1
112.5	0.6	0.5	0.4	0.3	0.2	0.1
100	0.7	0.6	0.5	0.4	0.3	0.2
87.5	0.9	0.8	0.7	0.5	0.4	0.3
75	1.0	1.0	0.9	0.7	0.6	0.5
62.5	1.5	1.4	1.1	1.0	0.8	0.7
50	2.0	1.8	1.6	1.3	1.1	0.9
37.5	3.0	2.6	2.3	2.0	1.7	1.4
25	4.7	4.2	3.5	3.0	2.8	2.3
12.5	10.2	9.0	8.0	7.0	6.0	5.0
	20	30	40	50	60	70
	Ambient-temperature (°C)					

Notes on Sizing for Selection of a Heat Sink

The heat generated by the load current must be dissipated by a suitable heat sink. It is imperative that the junction temperature of the semiconductor is maintained for all potential environmental temperatures of under 125°C. For this reason, it is important to keep the thermal resistance between the base plate of the semiconductor relay and the heat sink to a minimum.

To protect the semiconductor relay effectively from excess heating, a thermally conducting paste should be applied before installation to the base plate of the heat sink between semiconductor relay and heat sink.

From the tables below, select a suitable heat sink with the next lowest thermal resistance. Thus, it is ensured that the maximum junction temperature of 125°C is not exceeded. The load current in relation to the environmental temperature can be seen from the table.

Application Example
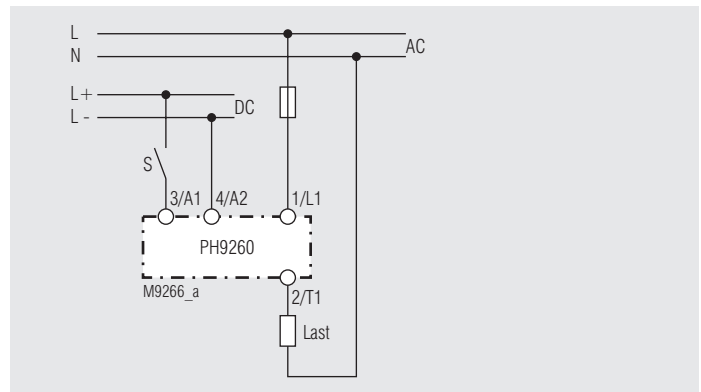
General Information

The service life and long-time reliability of a solid-state relay depends on its installation and use. Load type, load current, switching frequency, mains voltage and ambient temperature must be taken into account during the project design. To ensure the reliable operation of the devices, an exact analysis of the application and a calculation of the heat sink must be conducted in advance. Solid-state relays constantly produce heat during operation. The ambient conditions therefore require special attention. The choice of the correct heat sink is especially important since the constant overtemperature significantly reduces the service life of the devices. The use of a temperature switch is recommended if neither the load conditions nor the ambient temperatures are known. This switch is available as accessory and is inserted in a pocket on the bottom side.

Attention: The load output is not electrically separated from the mains even if no drive is present

Overload protection (Fig. 1)

The solid-state relay must be protected against short circuit by a separate solid-state fuse of coordination type 2. Choosing the I2t value (switch-off integral) of the fuse half as large as the I2t value of the semiconductor is recommended.

Overvoltage protection (Fig. 1)

Although the solid-state relays can withstand high peak voltages, it is better to switch an external varistor parallel to the load output. This is particularly recommended when switching inductive loads. The varistor voltage must be selected appropriate for the mains voltage. A wrong selection can create hazardous situations. As an option, the varistor is factory-installed.

Assembly on the heat sink (Fig. 2, Fig. 3)

A small amount of silicon-containing heat transfer compound is to be applied to the base plate to ensure a good thermal bond between solid-state relay and heat sink. As an alternative, a graphite foil can be placed between solid-state relay and heat sink.

⚠️ **Attention!**
Heat transfer compounds without silicon should not be used, since they may attack the plastic of the housing .

The solid-state relay is mounted to the heat sink using two M5x8 screws and matching washers. Both screws should be tightened in alternating fashion until a torque of 1 Nm is reached. After approx. one hour the screws need to be tightened further with a final torque of 2.5 Nm. This ensures that all excess heat transfer compound is squeezed out or that the graphite foil can well adapt to the contours of the surfaces.

Installation of the complete unit (Fig. 4)

The fins of the heat sink must be aligned in a manner allowing the unobstructed circulation of air. Without external fan, the fins must be aligned vertically to support natural convection.

Connection

	Control terminals	Load terminals
Screw:	M3 Pozidrive	M4 Pozidrive
Tightening torque:	0,5 Nm	1,2 Nm
Wire gauge:	1,5 mm^2	10 mm^2

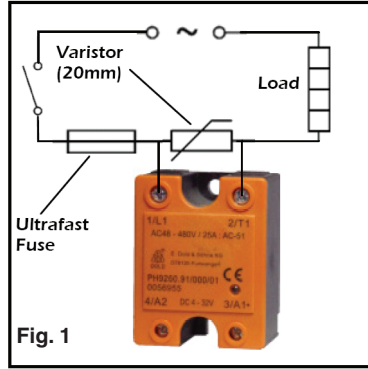⚠️ **Attention! When using pneumatic or electric power screwdrivers, their torque limit must be set correctly.**
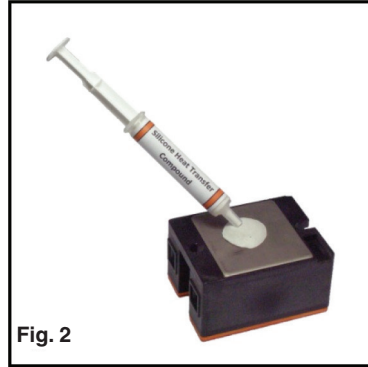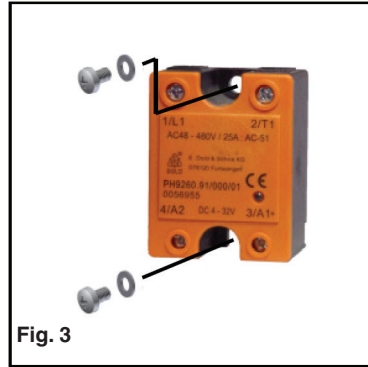

Fig. 1

Fig. 2

Fig. 3

Fig. 4

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